

1. Record Nr.	UNINA9910702487203321
Autore	Woodworth Andrew A.
Titolo	Characterization of 4H <000-1> silicon carbide films grown by solvent-laser heated floating zone // Andrew A. Woodworth [and four others]
Pubbl/distr/stampa	Cleveland, Ohio : , : National Aeronautics and Space Administration, Glenn Research Center, , 2012
Descrizione fisica	1 online resource (6 pages) : illustrations
Collana	NASA/TM ; ; 2012-217708
Soggetti	Silicon carbides Single crystals Crystal growth Laser heating X ray diffraction Diffraction patterns
Lingua di pubblicazione	Inglese
Formato	Materiale a stampa
Livello bibliografico	Monografia
Note generali	Title from title screen (viewed on Aug. 21, 2014). "September 2012." "Prepared for the 2012 Spring Meeting and Exhibit sponsored by the Materials Research Society, San Francisco, California, April 9-13, 2012."
Nota di bibliografia	Includes bibliographical references (page 6).